

# RS2AD THRU RS2MD

## Surface Mount Fast Recovery Rectifiers

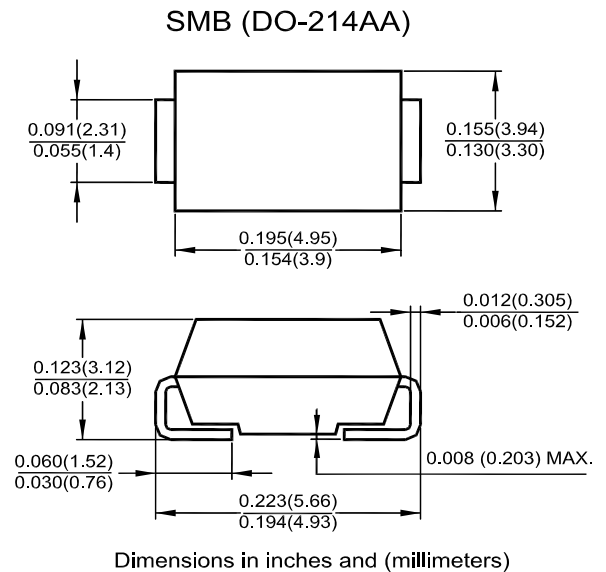
Reverse Voltage – 50 to 1000 V  
Forward Current – 2 A

### Features

- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- Fast switching for high efficiency
- Built-in strain relief, ideal for automated placement
- Low reverse leakage
- High forward surge current capability
- For surface mounted applications
- High temperature soldering guaranteed: 250 °C / 10 seconds at terminals.

### Mechanical Data

- **Case:** Molded plastic body, JEDEC SMB (DO-214AA)
- **Terminals:** Solder plated, solderable per MIL-STD-750, method 2026
- **Polarity:** Color band denotes cathode end.
- **Mounting Position:** Any



### Absolute Maximum Ratings and Characteristics

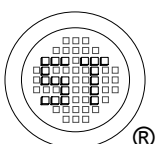
Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half-wave 60 Hz, resistive or inductive load. For capacitive load current derate by 20%.

Parameter	Symbols	RS2AD	RS2BD	RS2DD	RS2GD	RS2JD	RS2KD	RS2MD	Units
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current at $T_L = 90\text{ }^\circ\text{C}$	$I_{F(AV)}$	2							A
Peak Forward Surge Current 8.3 ms Single half Superimposed on Rated Load (JEDEC method)	$I_{FSM}$	50							A
Maximum Instantaneous Forward Voltage at 2 A	$V_F$	1.3							V
Maximum DC Reverse Current $T_a = 25\text{ }^\circ\text{C}$ at Rated DC Blocking Voltage $T_a = 100\text{ }^\circ\text{C}$	$I_R$	5 50							$\mu\text{A}$
Maximum Reverse Recovery Time <sup>1)</sup>	$t_{rr}$	150			250	500			ns
Typical Junction Capacitance <sup>2)</sup>	$C_j$	50							pF
Typical Thermal Resistance <sup>3)</sup>	$R_{\theta JA}$	20							$^\circ\text{C/W}$
Operating Junction Temperature Range	$T_j$	- 65 to + 150							$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	- 65 to + 150							$^\circ\text{C}$

<sup>1)</sup> Reverse recovery condition  $I_F = 0.5\text{ A}$ ,  $I_R = 1\text{ A}$ ,  $I_{rr} = 0.25\text{ A}$ .

<sup>2)</sup> Measured at 1 MHz and applied reverse voltage of 4 V.

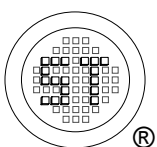
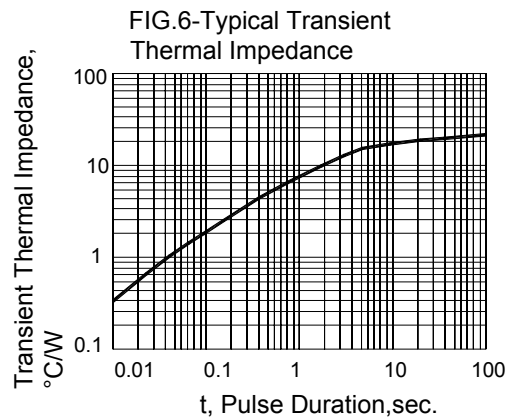
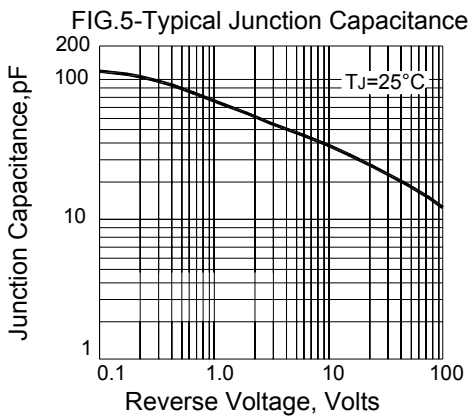
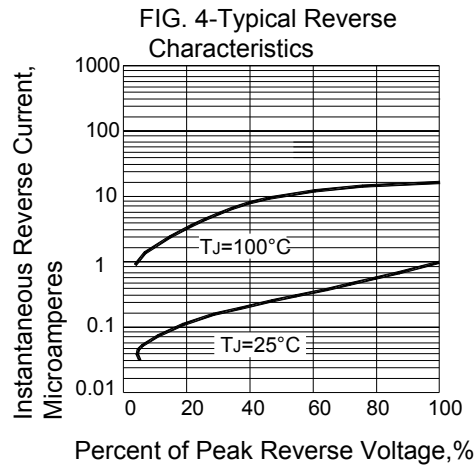
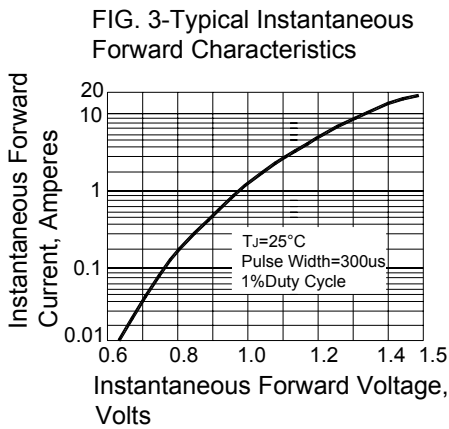
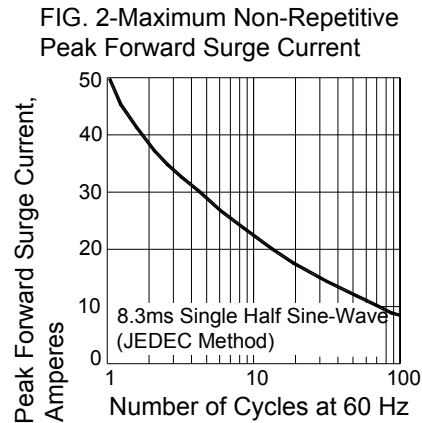
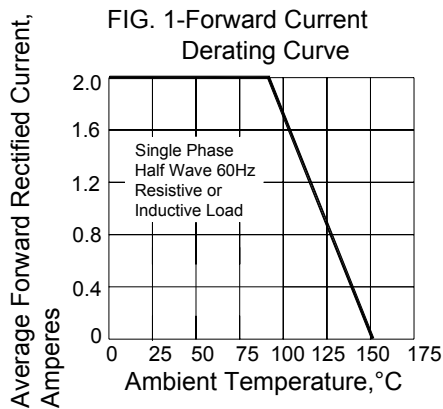
<sup>3)</sup> P.C.B mounted with  $0.2 \times 0.2\text{"} (5 \times 5\text{ mm})$  copper pad areas.



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